NSN 5961-01-058-7783

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View Online at https://aerobasegroup.com/nsn/5961-01-058-7783 **Inclosure Material:** Metal **Overall Length:** Between 0.320 inches and 0.468 inches Overall Diameter: 0.440 inches **Function For Which Designed:** Switching **Mounting Facility Quantity: Internal Configuration:** Junction contact-darlington connected Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-59 **Mounting Method:** Threaded stud **Features Provided:** Mounting hardware **Overall Width Across Flats:** Between 0.424 inches and 0.437 inches **Thread Size:** 0.190 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 120.0 collector to base voltage/static/emitter open and 80.0 collector to emitter voltage/static/base open and 6.0 emitter to base voltage, static, collector open **Current Rating Per Characteristic:** Between 1.00 amperes source cutoff current and 5.00 amperes source cutoff current **Power Rating Per Characteristic:** 2.0 watts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius ambient air **Special Features:** Junction pattern arrangement: npn **Test Data Document:** 30003-446as177 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Thread Series Designator:**

Unf

Terminal Type And Quantity:

3 tab, solder lug

Shelf Life:

N/a

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Demilitarization:

No

Fiig:

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